Single Supply Voltage, RS-232 Transceiver

DESCRIPTION

MAX232 is compatible with RS-232 standard, and consists of dual transceiver. Each receiver converts TIA/EIA-232-E levels into 5V TTL/CMOS levels. Each driver converts TT-L/COMS levels into TIA/EIA-232-E levels. The MAX232 is characterized for operation from -40°C to +85°C for all packages.

MAX232 is purposed for application in high-performance information processing systems and control devices of wide application.

C1+ 1 16 VCC V+ 2 15 GND C1- 3 14 T1out C2+ 4 MAX232 12 R1out V- 6 11 T1IN T2out 7 R2IN 8 9 R2out (Top View)

PIN CONFIGURATION

FEATURES

- Input voltage levels are compatible with standard CMOS levels
- Output voltage levels are compatible with EIA/TIA-232-E levels
- Single Supply voltage: 5V
- Low input current: 0.1µA at TA= 25 °C
- Output current: 24mA
- Latching current not less than 450mA at T_A= 25°C
- The transmitter outputs and receiver inputs are protected to ±15kV Air ESD

APPLICATION

- Battery-Powered RS232 Systems
- Terminals
- Modems
- Computers

ORDERING INFORMATION

Temperature Range	Package		Orderable Device	Package Qty
	SOP16L		MAX232D	50Units/Tube
-40°C to +85°C		Pb-Free	MAX232DR	3000Units/R&T
	DIP16L		MAX232N	25Units/Tube

PIN DESCRIPTION

No.	Name	Function
1	C1+	External capacitance of positive voltage multiplier unit
2	V+	Output of positive voltage of multiplier unit
3	C1-	External capacitance of positive voltage multiplier unit
4	C2+	External capacitance of negative voltage multiplier unit
5	C2-	External capacitance of negative voltage multiplier unit
6	V-	Output of negative voltage of multiplier unit
7	Т2оит	Output of transmitter data (levels RS – 232)
8	R2IN	Input of receiver data (levels RS – 232)
9	R2оит	Output of receiver data (levels TTL/CMOS)
10	T2 _{IN}	Input of transmitter data (levels TTL/CMOS)
11	T1 _{IN}	Input of transmitter data (levels TTL/CMOS)
12	R1оит	Output of receiver data (levels TTL/CMOS)
13	R1 _{IN}	Input of receiver data (levels RS – 232)
14	Т1оит	Output of transmitter data (levels RS – 232)
15	GND	Ground
16	Vcc	Supply voltage

ABSOLUTE MAXIMUM RATINGS

Parame	Symbol	Min	Max	Unit	
Supply voltage	ply voltage		-0.3	6.0	V
Transmitter high ou	tput voltage	V+	Vcc -0.3	14	V
Transmitter low out	V-	-0.3	-14	V	
Transmitter input voltage		VTIN	-0.3	(V+) + 0.3	V
Receiver input volta	Receiver input voltage		-30	30	V
	DIP package	D-		842	
Dissipated power	SOP package	PD		762	mW
Output current of transmitter short circuit		Isc		Continuously	mA
Storage temperature	e ranges	T _{stg}	-60	150	°C

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Max	Unit
Supply voltage	Vcc	4.5	5.5	V
Transmitter output high voltage	V+	5.0		V
Transmitter output low voltage	V-	-5.0		V
Transmitter input voltage	VTIN	0	Vcc	V
Receiver input voltage	VRIN	-30	30	V
Transmitter short circuit output current	Isc		±60	mA



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DC ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Conditions		25°C		-40°C to +85°C		Unit
					Max	Min	Max	
Supply Current	Icc	Vcc =5.0V, VIL	_ = 0V		10.0		14.0	mA
Receiver								
Hysteresis voltage	Vh	Vcc =5.0V		0.2	0.9	0.2	1.0	٧
On (operation) voltage	Von	Vo ≤ 0.1V, loL	. ≤ 20 mA		2.4		2.3	V
Off (dropout) voltage	Voff	Vo ≥ Vcc -0.1 Іон ≤ -20 mA	V,	0.8		0.9		V
Output low voltage	Vol	IoL = 3.2mA, V	Vcc = 4.5V,		0.3		0.4	V
Output high voltage	Vон	Iон = -1.0mA, VIL = 0.8V	Iон = -1.0mA, Vcc = 4.5V,			3.5		V
Input resistance	Rı	Vcc =5.0V		3.0	7.0	3.0	7.0	kΩ
Transmitter								
Output low voltage	Vol	$V_{CC} = 4.5V, V$ $R_L = 3.0k\Omega$	IH = 2.0V,		-5.2		-5.0	V
Output high voltage	Vон	$V_{CC} = 4.5V, V$ $R_L = 3.0k\Omega$	ıL = 2.0V,	5.2		5.0		V
Input low current	lıL	Vcc =5.5V, VII	L = 0V		-1.0		-10.0	μΑ
Input high current	Іін	Vcc =5.5V, VII	H = Vcc		1.0		10.0	μA
Speed of output front change	SR	Vcc =5.0V, C _L =50 ~ 1000pF R _L = $3.0 \sim 7.0$ kΩ		3.0	30	2.7	27	V/µs
Output resistance	Ro	V _{CC} = V+ = V- = 0 V, V _O = ±2V		350		300		Ω
Short circuit output current	Isc	Vcc =5.5V	V _I = V _{CC} V _I = 0 V		-50 50		-60 60	mA
Speed of information transmission	ST	$V_0 = 0V$ $V_1 = 0 V$ $V_{CC} = 4.5V$, $C_L = 1000pF$ $R_L = 3.0k\Omega$, $t_W = 7ms$ (for extreme $t_W = 8ms$)		140		120	00	kbits/s

AC ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Conditions		25°C		-40°C to +85°C	
			Min	Max	Min	Max	
Signal propagation delay time when switching on (off)	tphlr (tplhr)	$V_{CC} = 4.5V, C_L = 150pF$ $V_{IL} = 0V, V_{IH} = 3.0V$ $t_{LH} = t_{HL} \le 10ns$		9.7		10	ms
Signal propagation delay time when switching on (off)	tрнгт (tргнт)	$V_{CC} = 4.5V, C_L = 150pF$ $V_{IL} = 0V, V_{IH} = 3.0V$ $t_{LH} = t_{HL} \le 10 \text{ ns}$		5.0		6.0	ms



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CAPACITANCE

Parameter	Symbol	Test Conditions	Value	Unit
Input capacitance	CIN		9.0	pF
Dynamic capacitance	CPD	Vcc=5.0V	90	pF

TIMING DIAGRAM

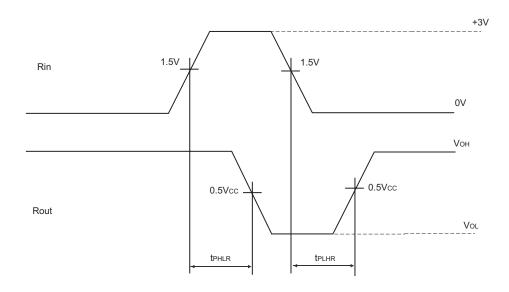


Figure 1. Waveforms for tPHLR and tPLHR Measurement

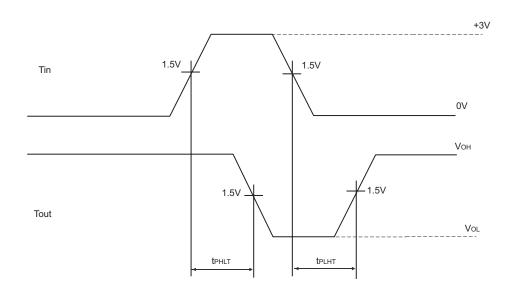


Figure 2. Waveforms for tPHLT and tPLHT Measurement

TYPICAL APPLICATION

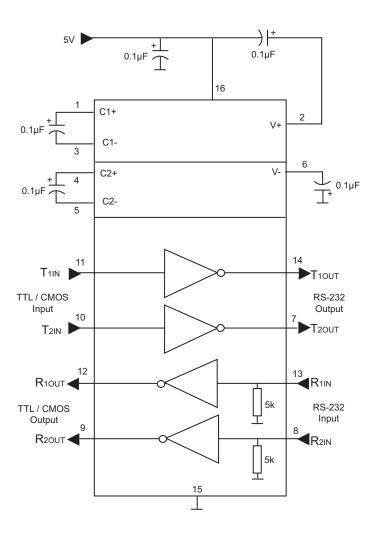
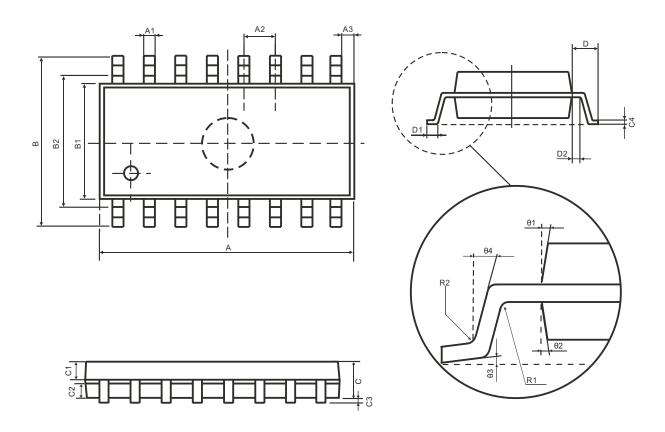


Figure 4. Application circuit

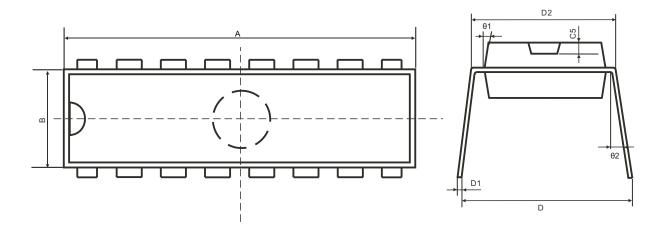
PHYSICAL DIMENSIONS SOP16L

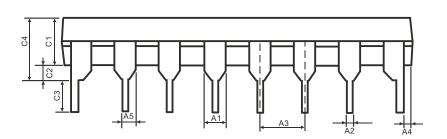


Comple ed	Dimensio	on(mm)		Dimensi	on(mm)
Symbol	Min	Max	Symbol	Min	Max
А	9.90	10.10	C4	0.20	(TYP)
A1	0.36	0.46	D	1.05	(TYP)
A2	1.27	(TYP)	D1	0.40	0.70
А3	0.35	(TYP)	D2	0.22	0.42
В	5.84	6.24	R1	0.15(TYP)	
B1	3.84	4.04	R2	0.15(TYP)	
B2	5.00(TYP)	θ1	8°(TYP)	
С	1.35	1.55	θ2	8°(TYP)	
C1	0.61	0.71	θ3	4°(TYP)	
C2	0.54	0.64	04	15°(TYP)	
C3	0.10	0.25			



DIP16L





	Dimension(mm)		O	Dimensi	on(mm)
Symbol	Min	Max	Symbol	Min	Max
Α	19.05	19.45	C3	3.00	3.60
A1	1.52(TYP)	C4	3.85	4.45
A2	0.46(TYP)	C5	0.80	(TYP)
А3	2.54((TYP)	D	8.10	8.60
A4	0.51((TYP)	D1	0.20	0.35
A5	0.99(TYP)	D2	7.62	(TYP)
В	6.20	6.60	θ1	8°(TYP)
C1	3.30	3.70	θ2	5°(TYP)	
C2	0.51(TYP)			



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